



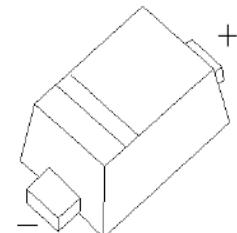
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MAITUO ELECTRONIC

## RB520S-30 Schottky barrier Diode



### FEATURES

- Small surface mounting type
- Low  $I_R$
- High reliability



MARKING: B

SOD-523

### Maximum Ratings and Electrical Characteristics, Single Diode @Ta=25°C

Parameter	Symbol	Limit	Unit
DC reverse voltage	$V_R$	30	V
Mean rectifying current	$I_o$	200	mA
Non-repetitive Peak Forward Surge Current@t=8.3ms	$I_{FSM}$	1	A
Power dissipation	$P_D$	150	mW
Thermal resistance junction to ambient	$R_{\theta JA}$	667	°C/W
Operating Junction Temperature Range	$T_j$	-40 ~ +125	°C
Storage Temperature Range	$T_{stg}$	-55 ~ +150	°C

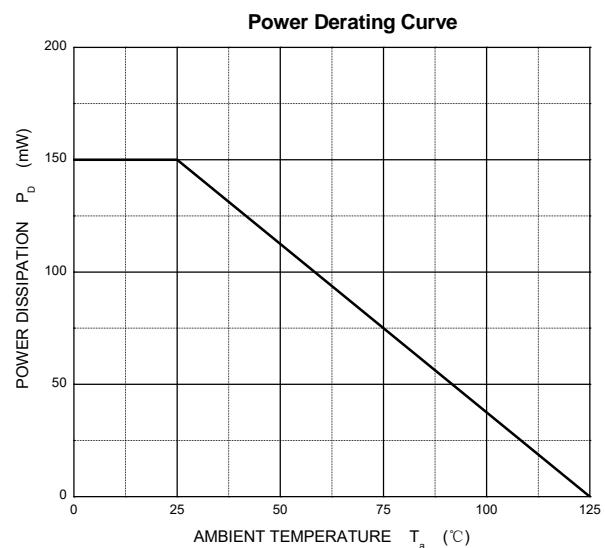
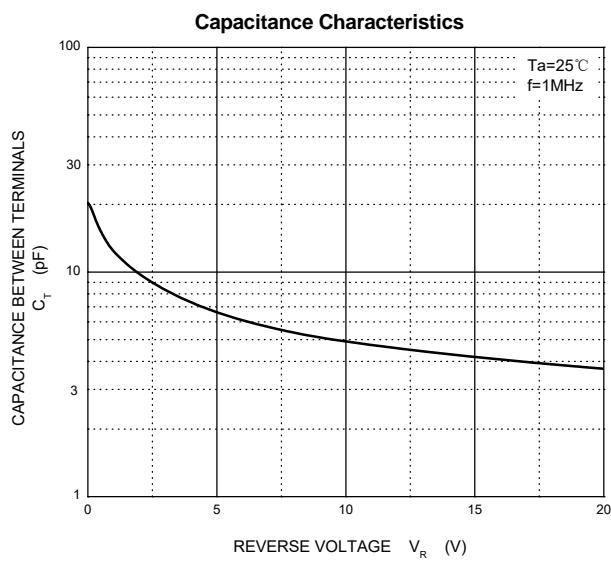
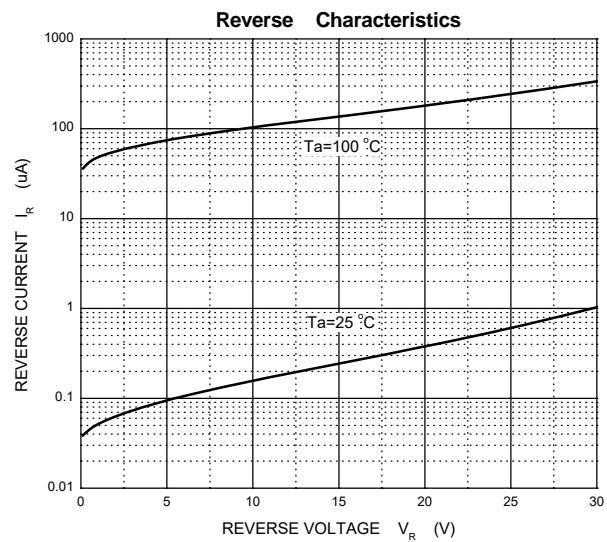
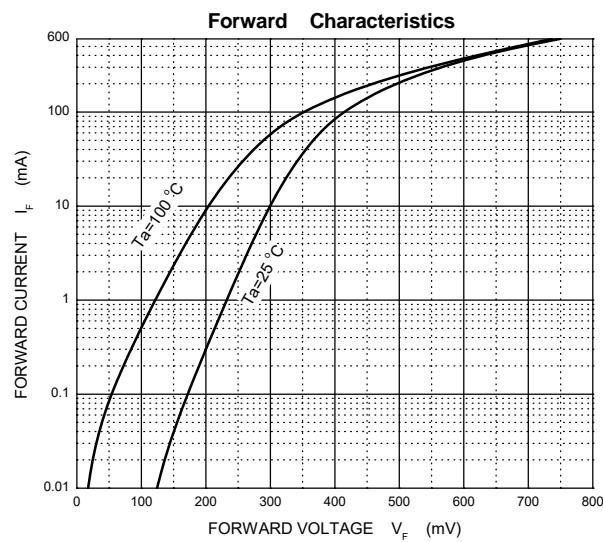
### Electrical Ratings @Ta=25°C

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Forward voltage	$V_F$			0.6	V	$I_F=200mA$
Reverse current	$I_R$			1	μA	$V_R=10V$



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## Typical Characteristics



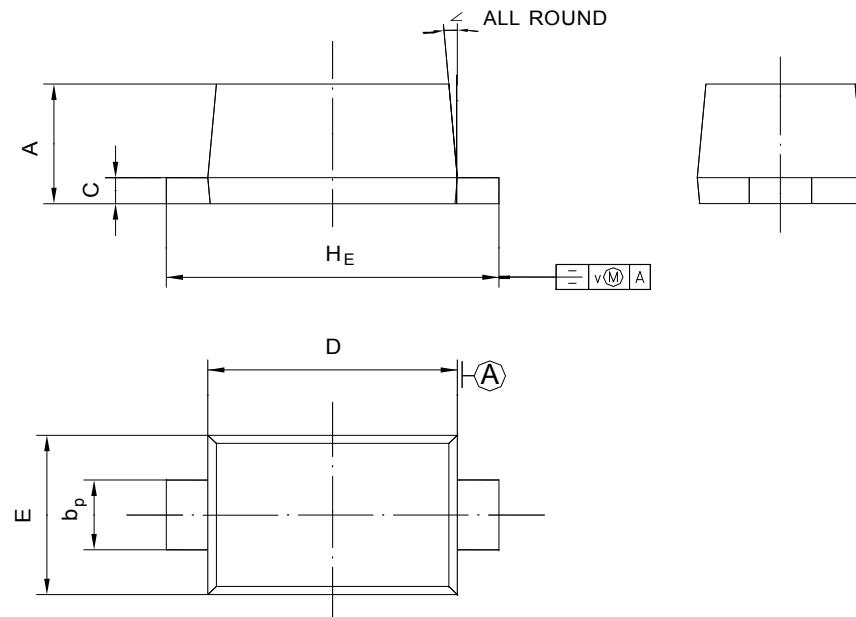


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## PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-523



UNIT	A	b <sub>p</sub>	C	D	E	H <sub>E</sub>	V	∠
mm	0.68	0.4	0.135	1.25	0.85	1.7	0.1	5°
	0.58	0.3	0.100	1.15	0.75	1.5		